

CMLDM5757

SURFACE MOUNT SILICON
DUAL P-CHANNEL
ENHANCEMENT-MODE
MOSFET



SOT-563 CASE

APPLICATIONS:

- Load switch/Level shifting
- Battery charging
- Boost switch
- Electro-luminescent backlighting

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	8.0	V
Continuous Drain Current (Steady State)	I_D	430	mA
Maximum Pulsed Drain Current ($t_p=10\mu\text{s}$)	I_{DM}	750	mA
Power Dissipation (Note 1)	P_D	350	mW
Power Dissipation (Note 2)	P_D	300	mW
Power Dissipation (Note 3)	P_D	150	mW
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
Thermal Resistance (Note 1)	Θ_{JA}	357	$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS PER TRANSISTOR: ($T_A=25^\circ\text{C}$)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{GSSF}, I_{GSSR}	$V_{GS}=4.5\text{V}, V_{DS}=0$		2.0	μA
I_{DSS}	$V_{DS}=16\text{V}, V_{GS}=0$		1.0	μA
BV_{DSS}	$V_{GS}=0, I_D=250\mu\text{A}$	20		V
$V_{GS(\text{th})}$	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	0.45	1.0	V
V_{SD}	$V_{GS}=0, I_S=350\text{mA}$		1.2	V
$r_{DS(\text{ON})}$	$V_{GS}=4.5\text{V}, I_D=430\text{mA}$		0.9	Ω
$r_{DS(\text{ON})}$	$V_{GS}=2.5\text{V}, I_D=300\text{mA}$		1.2	Ω
$r_{DS(\text{ON})}$	$V_{GS}=1.8\text{V}, I_D=150\text{mA}$		2.0	Ω
C_{rss}	$V_{DS}=16\text{V}, V_{GS}=0, f=1.0\text{MHz}$	20		pF
C_{iss}	$V_{DS}=16\text{V}, V_{GS}=0, f=1.0\text{MHz}$	175		pF
C_{oss}	$V_{DS}=16\text{V}, V_{GS}=0, f=1.0\text{MHz}$	30		pF

Notes: (1) Ceramic or aluminum core PC Board with copper mounting pad area of 4.0mm²

(2) FR-4 Epoxy PC Board with copper mounting pad area of 4.0mm²

(3) FR-4 Epoxy PC Board with copper mounting pad area of 1.4mm²



www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMLDM5757 consists of dual P-Channel enhancement-mode silicon MOSFETs designed for high speed pulsed amplifier and driver applications. These MOSFETs offer very low $r_{DS(\text{ON})}$ and low threshold voltage.

MARKING CODE: 77C

FEATURES:

- ESD protection up to 1800V (Human Body Model)
- 350mW power dissipation
- Very low $r_{DS(\text{ON})}$
- Low threshold voltage
- Logic level compatible
- Small, SOT-563 surface mount package
- Complementary dual N-Channel device: CMLDM3737

CMLDM5757

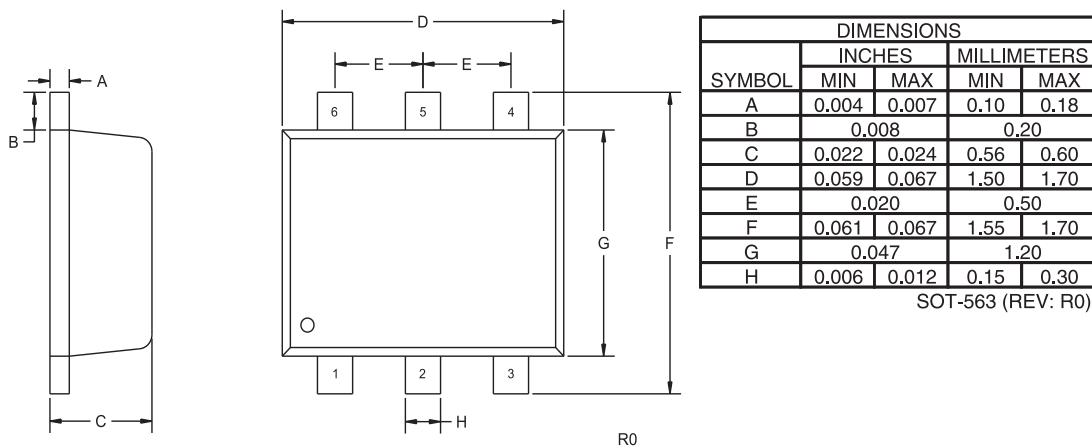
**SURFACE MOUNT SILICON
DUAL P-CHANNEL
ENHANCEMENT-MODE
MOSFET**

**Central
Semiconductor Corp.**

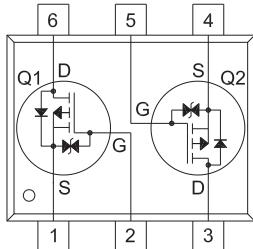
ELECTRICAL CHARACTERISTICS PER TRANSISTOR - Continued: ($T_A=25^\circ C$)

ELECTRICAL CHARACTERISTICS FOR TA=25°C		CONTINUED (TA=25°C)		
SYMBOL	TEST CONDITIONS	TYP	MAX	UNITS
Q _{g(tot)}	V _{DS} =10V, V _{GS} =4.5V, I _D =200mA	1.2		nC
Q _{gs}	V _{DS} =10V, V _{GS} =4.5V, I _D =200mA	0.24		nC
Q _{gd}	V _{DS} =10V, V _{GS} =4.5V, I _D =200mA	0.36		nC
t _{on}	V _{DD} =10V, V _{GS} =4.5V, I _D =215mA, R _G =10Ω	38		ns
t _{off}	V _{DD} =10V, V _{GS} =4.5V, I _D =215mA, R _G =10Ω	48		ns

SOT-563 CASE - MECHANICAL OUTLINE



PIN CONFIGURATION



LEAD CODE:

- 1) Source Q1
 - 2) Gate Q1
 - 3) Drain Q2
 - 4) Source Q2
 - 5) Gate Q2
 - 6) Drain Q1

MARKING CODE: 77C

R2 (5-June 2013)

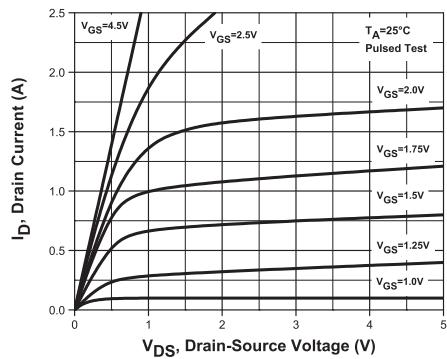
CMLDM5757

**SURFACE MOUNT SILICON
DUAL P-CHANNEL
ENHANCEMENT-MODE
MOSFET**

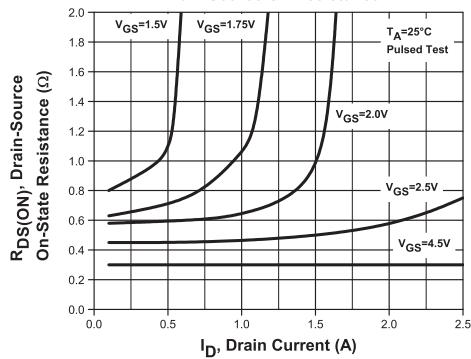


TYPICAL ELECTRICAL CHARACTERISTICS

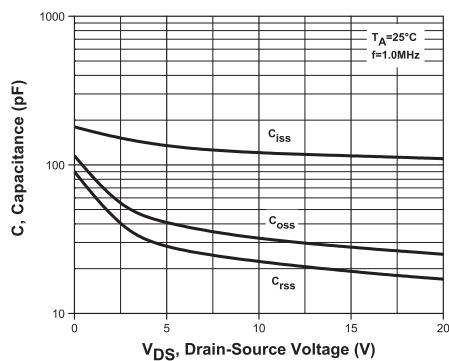
Output Characteristics



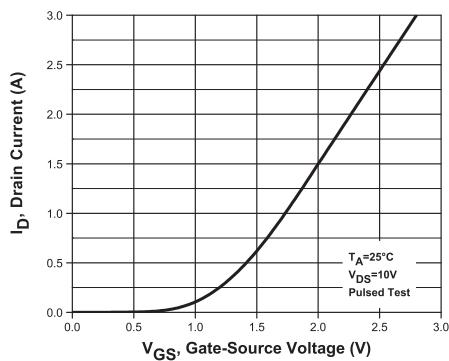
Drain Source On Resistance



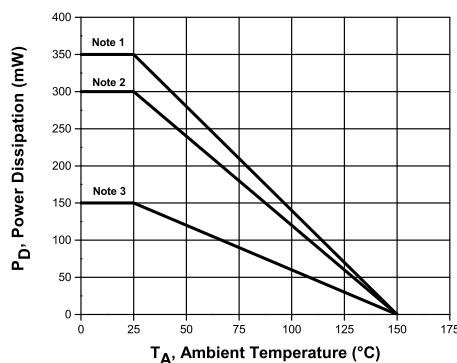
Capacitance



Transfer Characteristics



Power Derating



R2 (5-June 2013)

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by Central Semiconductor manufacturer:

Other Similar products are found below :

[614233C](#) [648584F](#) [IRFD120](#) [JANTX2N5237](#) [2N7000](#) [FCA20N60_F109](#) [FDZ595PZ](#) [2SK2545\(Q,T\)](#) [405094E](#) [423220D](#)
[TPCC8103,L1Q\(CM](#) [MIC4420CM-TR](#) [VN1206L](#) [614234A](#) [715780A](#) [NTNS3166NZT5G](#) [SSM6J414TU,LF\(T](#) [751625C](#)
[IPS70R2K0CEAKMA1](#) [BUK954R8-60E](#) [DMN3404LQ-7](#) [NTE6400](#) [SQJ402EP-T1-GE3](#) [2SK2614\(TE16L1,Q\)](#) [2N7002KW-FAI](#)
[DMN1017UCP3-7](#) [EFC2J004NUZTDG](#) [ECH8691-TL-W](#) [FCAB21350L1](#) [P85W28HP2F-7071](#) [DMN1053UCP4-7](#) [NTE221](#) [NTE2384](#)
[NTE2903](#) [NTE2941](#) [NTE2945](#) [NTE2946](#) [NTE2960](#) [NTE2967](#) [NTE2969](#) [NTE2976](#) [NTE455](#) [NTE6400A](#) [NTE2910](#) [NTE2916](#) [NTE2956](#)
[NTE2911](#) [US6M2GTR](#) [TK10A80W,S4X\(S](#) [SSM6P69NU,LF](#)